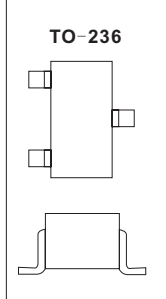
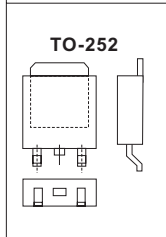
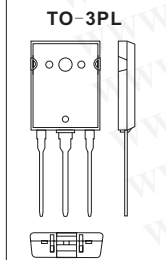
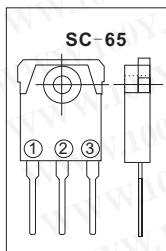
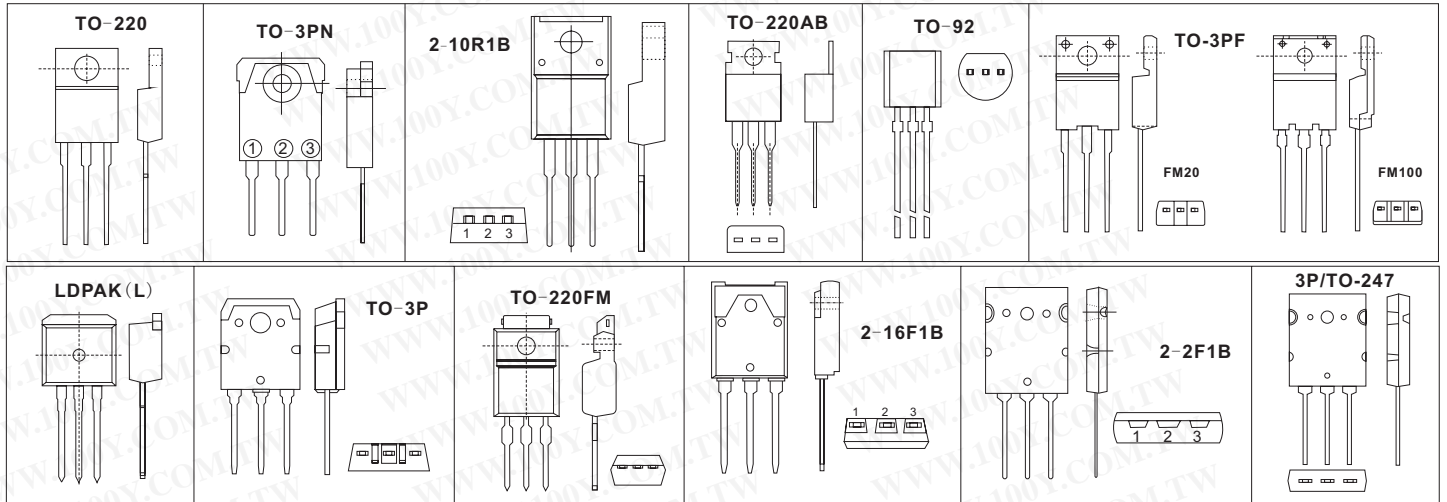


Semiconductors-Discretes

2SK~ Series Power MOSFET

Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	N/P Ch.	Pins/Package	Pd(max)	Vds	Vgss	Id(max)	Rds(on)(max.) Ω
29187	2SK1082	FUJITSU	N-channel silicon power MOSFET	N Ch.	TO-3P/3PS	125W		+/-30V	18A	2.8
15666	2SK1117	TOSHIBA	N-channel silicon power MOSFET	N	TO-220	100W	600V		6A	
29175	2SK1118	TOSHIBA	N-channel silicon power MOS-FET	N Ch.	TO-220F	45W	600V	+/-30V	24A	1.25
15665	2SK1119	TOSHIBA	Silicon N channel field effect transistor for high speed, high current switching applications, DC-DC converter and motor drive applications	N	TO-220	100W	1000V	±20V	4A	
15127	2SK1120	TOSHIBA	Silicon N channel field effect transistor for high speed, high current switching applications, DC-DC converter and motor drive applications	N	3P/TO-3PN	150W	1000V	±20V	8 A	
14852	2SK1153	HITACHI	Power switching MOSFET	N	3P/TO-220AB	30W	450V	±30V	3A	
14853	2SK1155	HITACHI	Power switching MOSFET	N	3P/TO-220AB	50W	450V	±30V	5A	
14854	2SK1157	HITACHI	Power switching MOSFET	N	3P/TO-220AB	60W	450V	±30V	7A	
35862	2SK117	TOSHIBA	N channel junctions	N	TO-92	0.3W		-50V	14mA	
6013	2SK117-GR	TOSHIBA	Silicon N Channel Junction Type	N	3P/TO-92	300mW	-50V	1.5V	10mA	
28472	2SK1181	SanKen	N channel silicon power MOS-FET	N	TO-3PF	85 (Tc = 25oC)W		±20V	250uA	0.4
28683	2SK1221	TOSHIBA	Toshiba_N channel silicon power MOS-FET	N	3P/TO-220AB	80W	250V	±30V	10A	
44794	2SK1221	NEC	PNP Silicon epitaxial transistor	PNP	TO-92	1	140			
6031	2SK1221	Fuji Elect	N-channel silicon power MOSFET	N	3P/TO-220AB	80W	250V	±30V	10A	
14855	2SK1313S	HITACHI	Power switching MOSFET	N	D2PAK	50W	450V	±30V	±10μA	
28418	2SK1317	HITACHI	S	N	TO-3P			±20V	2.5 A	12Ω
47611	2SK1318	HITACHI	Silicon N Channel MOS FET High Speed Power Switching	N	3P/TO-220FM	35W	120V	±20V	20A	
39413	2SK1336	HITACHI	Silicon N-Channel MOS FET	N	TO-92	400 mW	60V	±20V	0.3A	
16620	2SK1339	HITACHI	High speed power switching	N	3P/TO-3PN	80W	900V	±30V	3A	
6033	2SK1341	HITACHI	Power switching MOSFET	N	3P/TO-3PN	100W	900V	±30V	6A	
15663	2SK1358	TOSHIBA	Silicon N-channel MOS type	N	TO-3P	150W	900V	±30V	9A	
35865	2SK1365	TOSHIBA	FET, Silicon N Channel MOS Type	N	ISO3P	90W	1000V	20V	7A	1.5 Ω
19459	2SK1385	Fuji Elect	Power switching MOSFET	N	3P/TO-3PN	900mW	100V	±20V	600mA	
14856	2SK1403	HITACHI	Power switching MOSFET	N	3P/TO-3PN	100W	650V	±30V	±10μA	
35867	2SK1489	TOSHIBA	N channel mos type (chopper regulator, high speed, high current switching applications)	N	TO-3	200W	1000V	30V	12A	0.8 Ω
16628	2SK1500	NEC	N-Channel	N	3P/TO-247	125W	450V	±30V	18A	
37227	2SK1506	FUJITSU	N-channel silicon power mosfet	N	SC-65	150W	120V	±20V	50A	45mΩ
15664	2SK1507	FUJITSU	Fuji power MOS-FET	N	TO-220	50W	600V	±30V	9A	
38932	2SK1522	HITACHI	N-channel silicon mosfet	N	TO-3PL		500V	±30V	50A	0.11Ω
6036	2SK1529		Silicon N channel field effect transistor for high power amplifier applications	N	3P/TO3PN	120W	180V	±20V	10A	
14858	2SK1667	HITACHI	Power switching MOSFET	N	3P/TO-220AB	50W	250V	±30V	7A	
40029	2SK170	TOSHIBA	N channel field effect transistor	N-Ch.	TO-92	400mW	10V	-30 V	10mA	
40381	2SK170GR	TOSHIBA	N channel field effect transistor	N-Ch.	TO-92	400mW	-40V		10mA	
24058	2SK1719		Power MOSFET		TO-252					
15667	2SK1794	NEC	N-MOS/600V/6A/100W	N	TO-3P	150W	900V		5A	
32155	2SK1821	FUJITSU	N-channel power MOSFET	N	TO-220	30W	600V	±25V	2A	6.5
15646	2SK1940	Fuji Elect	power amplifier applications	N	3P/TO-3P	125W	600V	600V	12A	0.75

